

TRIPLE DIFFUSED PLANER TYPE
HIGH VOLTAGE,HIGH SPEED SWITCHING

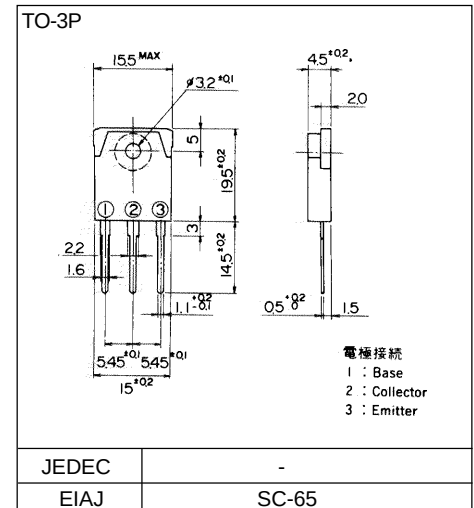
Features

- High voltage,High speed switching
- High reliability

Applications

- Switching regulators
- Ultrasonic generators
- High frequency inverters
- General purpose power amplifiers

Outline Drawings



Maximum ratings and characteristics

Absolute maximum ratings (Tc=25°C unless otherwise specified)

Item	Symbol	Ratings	Unit
Collector-Base voltage	V _{CB0}	500	V
Collector-Emitter voltage	V _{CEO}	400	V
Collector-Emitter voltage	V _{CEO(SUS)}	400	V
Emitter-Base voltage	V _{EB0}	7	V
Collector current	I _C	15	A
Base current	I _B	5	A
Collector power dissipation	P _C	80	W
Operating junction temperature	T _j	+150	°C
Storage temperature	T _{stg}	-65 to +150	°C

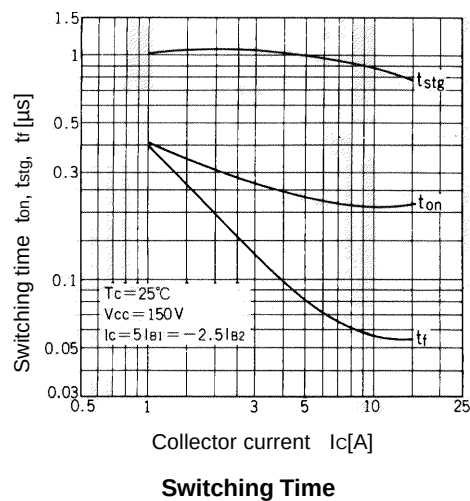
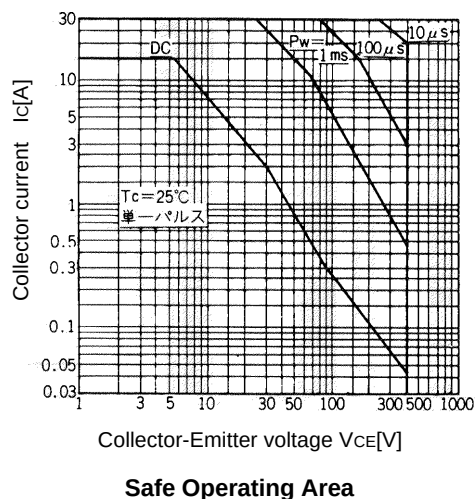
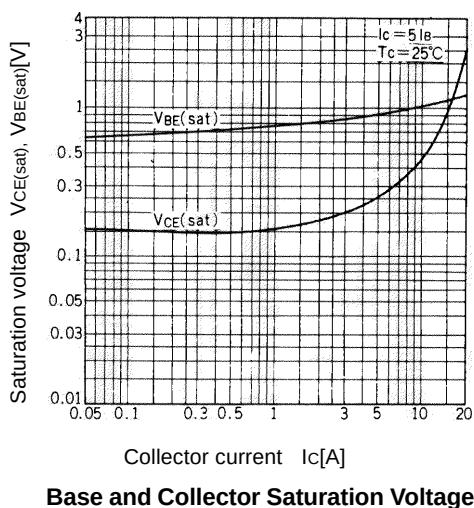
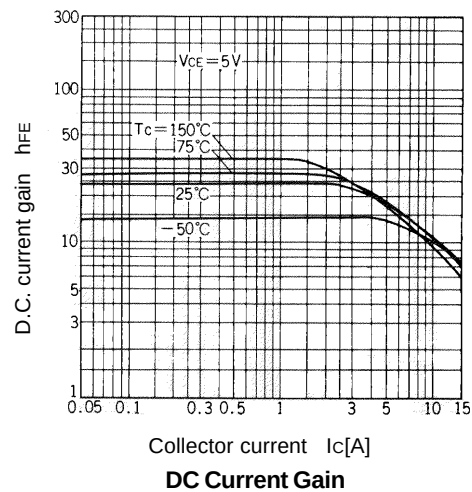
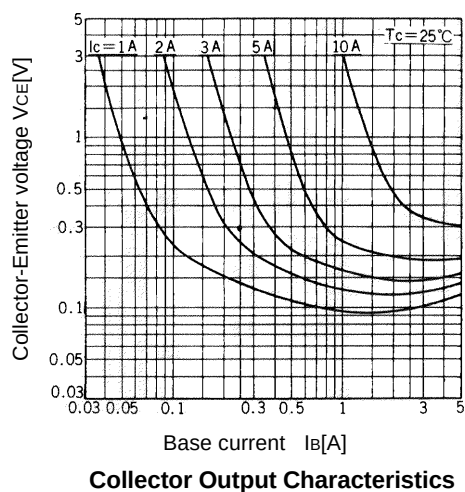
Electrical characteristics (Tc =25°C unless otherwise specified)

Item	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Collector-Base voltage	V _{CB0}	I _{CBO} = 1mA	500			V
Collector-Emitter voltage	V _{CEO}	I _{CEO} = 10mA	400			V
Collector-Emitter voltage	V _{CEO(SUS)}	I _C = 0.2A	400	-		V
Emitter-Base voltage	V _{EB0}	I _{EBO} = 1mA	7	-		V
Collector-Base leakage current	I _{CBO}	V _{CB0} = 500V		-	1.0	mA
Emitter-Base leakage current	I _{EBO}	V _{EB0} = 7V		-	1.0	mA
D.C. current gain	h _{FE}	I _C = 6A, V _{CE} = 5V	10			
Collector-Emitter saturation voltage	V _{CE(Sat)}	I _C = 6A, I _B = 1.2A			1.0	V
Base-Emitter saturation voltage	V _{BE(Sat)}				1.5	V
*1	t _{on}	I _C = 7.5A, I _{B1} = 1.5A			0.5	μs
Switching time	t _{stg}	I _{B2} = -3A, R _L = 20 ohm			1.5	μs
	t _f	P _w = 20 μs Duty=<2%			0.15	μs

Thermal characteristics

Item	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal resistance	R _{th(j-c)}	Junction to case			1.56	°C/W

Characteristics



*1 Switching Time Test Circuit

